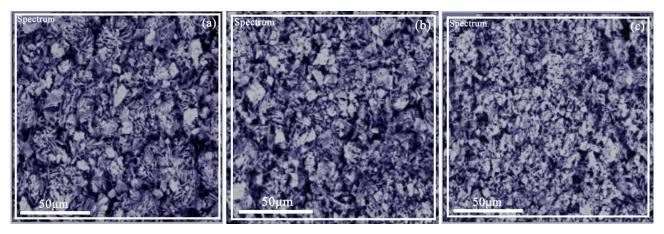
## Anion-exchange Synthesis of Thermoelectric Layered SnS<sub>0.1</sub>Se<sub>0.9-x</sub>Te<sub>x</sub> Nano/microstructures in Aqueous Solution; Complexity and Carrier Concentration.<sup>†</sup>; Supporting Information.

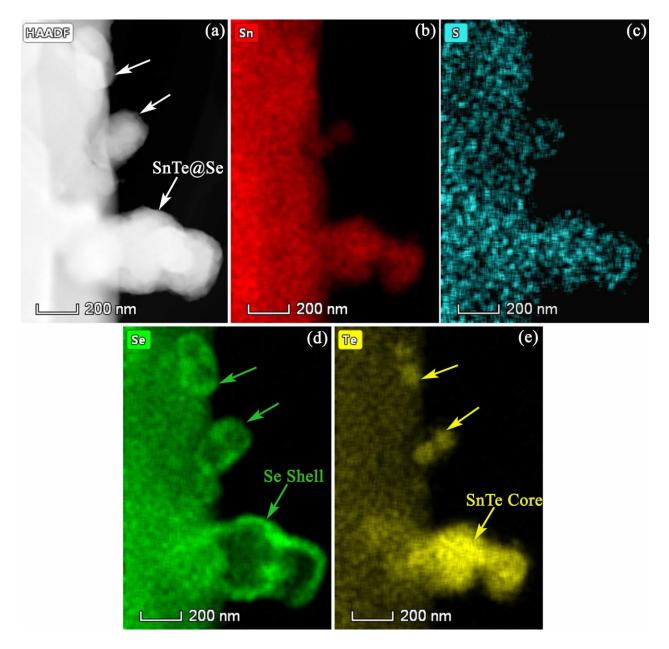
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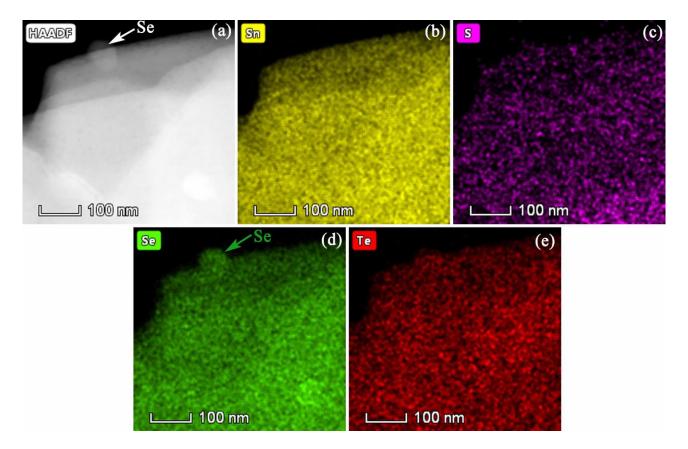
\*Corresponding author: Email: guang.han@cqu.edu.cn; Duncan.Gregory@glasgow.ac.uk



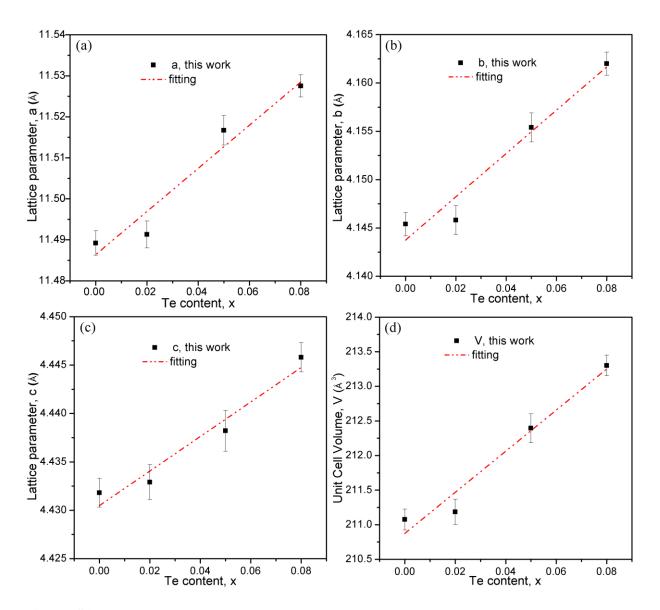
**Figure S1.** SEM images of  $SnS_{0.1}Se_{0.9-x}Te_x$  nano/microstructures revealing the positions where EDS spectra in Figure 2g-i were collected: (a) x = 0.02, (b) x = 0.05, and (c) c = 0.08.



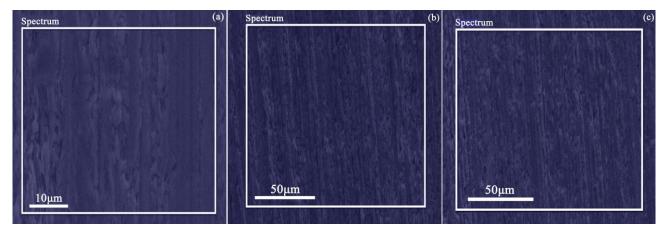
**Figure S2.** Characterization of  $SnS_{0.1}Se_{0.82}Te_{0.08}$  nano/microstructures: (a) HAADF-STEM image and (b-e) its corresponding element maps for Sn, S, Se and Te, respectively.



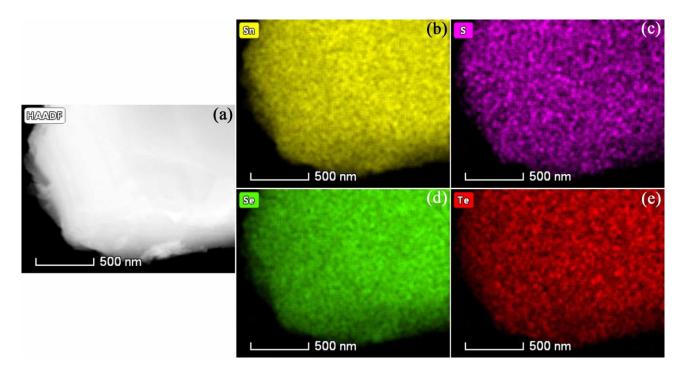
**Figure S3.** Characterization of SnS<sub>0.1</sub>Se<sub>0.82</sub>Te<sub>0.08</sub> nano/microstructures: (a) HAADF-STEM image and (b-e) its corresponding element maps for Sn, S, Se and Te, respectively.



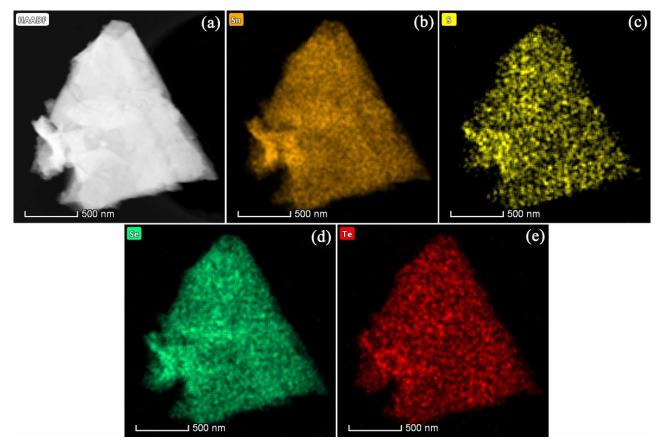
**Figure S4.** (a-c) Rietveld-refined lattice parameters and (d) unit cell volumes as a function of Te concentration (x) for SPS-SnS<sub>0.1</sub>Se<sub>0.9-x</sub>Te<sub>x</sub> (x = 0.02, 0.05, 0.08). The linear fits to each set of data are indicated by the red dashed/dotted line.



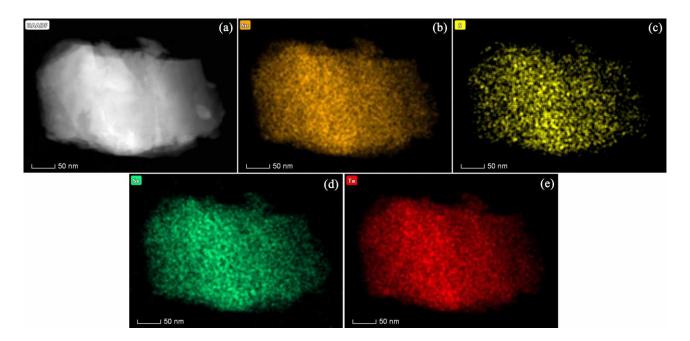
**Figure S5.** SEM images of  $SnS_{0.1}Se_{0.9-x}Te_x$  pellets revealing the positions where EDS spectra in Figure 5g- $^{\circ}$  were collected: (a) x = 0.02, (b) x = 0.05, and (c) c = 0.08.



**Figure S6.** Characterization of SPS-SnS $_{0.1}$ Se $_{0.88}$ Te $_{0.02}$ : (a) HAADF-STEM image and (b-e) its corresponding element maps for Sn, S, Se and Te, respectively.



**Figure S7.** Characterization of SPS-SnS<sub>0.1</sub>Se<sub>0.82</sub>Te<sub>0.08</sub> (peeled plate 1): (a) HAADF-STEM image and (b-e) its corresponding element maps for Sn, S, Se and Te, respectively.



**Figure S8.** Characterization of SPS-SnS<sub>0.1</sub>Se<sub>0.82</sub>Te<sub>0.08</sub> (peeled plate 2): (a) HAADF-STEM image and (b-e) its corresponding element maps for Sn, S, Se and Te, respectively.